

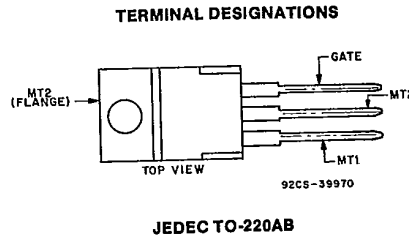
File Number 1314

T2800, T2802 Series

**High Voltage, 8-A Silicon Triacs**  
For Power-Control and Power-Switching Applications

Features:

- 800V, 125 Deg. C T<sub>J</sub> Operating
- High dv/dt and di/dt Capability
- Low Switching Losses
- High Pulse Current Capability
- Low Forward and Reverse Leakage
- Silicon Oxide Glass Multilayer Passivation System
- Advanced Unisurface Construction
- Precise Ion Implanted Diffusion Source



These RCA triacs are gate-controlled full-wave silicon switches utilizing a plastic case with three leads to facilitate mounting on printed-circuit boards. They are intended for the control of ac loads in such applications as motor controls, light dimmers, heating controls, and power-switching systems.

These devices are designed to switch from an off-state to an on-state for either polarity of applied voltage with positive or negative gate-triggering voltages.

The T2802 series triacs are characterized for I<sup>+</sup>, III<sup>-</sup> gate-triggering modes only and should suit a wide range of applications that employ diac or anode on/off triggering.

All series employ the plastic JEDEC TO-220AB package. The plastic package design provides not only ease of mounting but also low thermal impedance, which allows operation at high case temperatures and permits reduced heat-sink size.

MAXIMUM RATINGS, Absolute-Maximum Values:

	T2800A	T2800B	T2800C	T2800D	T2800E	T2800M	T2800N	
	T2802A	T2802B	T2802C	T2802D	T2802E	T2802M	T2802N	
V <sub>DR0M</sub> * (Gate Open, T <sub>J</sub> = -65 to 125°C)	100	200	300	400	500	600	800	V
I <sub>T(RMS)</sub> : T <sub>C</sub> = 105°C	8							A
I <sub>TSM</sub> (For one cycle of applied principal voltage):								A
60 Hz (sinusoidal), T <sub>C</sub> = 105°C	100							A
50 Hz (sinusoidal), T <sub>C</sub> = 105°C	85							A
For more than one cycle	See Figs. 2							
di/dt: V <sub>D</sub> = V <sub>DR0M</sub> , I <sub>G</sub> = 200 mA, t <sub>r</sub> = 0.1 μs	70							A/μs
i <sup>2</sup> t (At T <sub>C</sub> shown for I <sub>T(RMS)</sub> ):								A <sup>2</sup> s
t = 20 ms	55							A <sup>2</sup> s
= 2.5 ms	28							A <sup>2</sup> s
= 0.5 ms	16							A <sup>2</sup> s
I <sub>GTM†</sub>	4							A
P <sub>GM</sub> : (for 1 μs max., I <sub>GTM</sub> ≤ 4 A)	16							W
P <sub>G(AV)</sub>	0.35							W
T <sub>sig</sub>	-65 to 150							°C
T <sub>C</sub>	-65 to 125							°C
T <sub>T</sub> During soldering for 10 s max. (terminals and case)	225							°C

\*For either polarity of main terminal 2 voltage (V<sub>MT2</sub>) with reference to main terminal 1.  
†For either polarity of gate voltage (V<sub>G</sub>) with reference to main terminal 1.

Triacs

**T2800, T2802 Series**

**ELECTRICAL CHARACTERISTICS**

At Maximum Ratings Unless Otherwise Specified, and at Indicated Temperature

CHARACTERISTIC	SYMBOL	LIMITS			UNITS
		For All Types Unless Otherwise Specified			
		Min.	Typ.	Max.	
Peak Off-State Current: <sup>*</sup> Gate open, $T_J = 125^\circ\text{C}$ , $V_{\text{DROM}} = \text{Max. rated value}$	$I_{\text{DROM}}$	—	0.1	2	mA
Maximum On-State Voltage: <sup>*</sup> (See Fig. 4) For $i_T = 30\text{ A (peak)}$ , $T_C = 25^\circ\text{C}$ .....	$V_{\text{TM}}$	—	1.7	2	V
DC Holding Current: <sup>*</sup> Gate open, Initial principal current = 150 mA (dc), $V_D = 12\text{ V}$ , $T_C = 25^\circ\text{C}$ , T2800 series T2802 series For other case temperatures .....	$I_{\text{HO}}$	— —	15 20	30 60	mA
Critical Rate-of-Rise of Commutation Voltage: <sup>†</sup> For $V_D = V_{\text{DROM}}$ , $I_{\text{T(RMS)}} = 8\text{ A}$ , commutating $di/dt = 4.3\text{ A/ms}$ , gate unenergized, $T_C = 105^\circ\text{C}$ .....	$dv/dt$	4	10	—	V/ $\mu\text{s}$
Critical Rate-of-Rise of Off-State Voltage: <sup>*</sup> For $V_D = V_{\text{DROM}}$ , exponential voltage rise, and gate open, $T_C = 125^\circ\text{C}$ T2800B, T2802B .....	$dv/dt$	100	300	—	V/ $\mu\text{s}$
T2800C, T2802C .....		85	275	—	
T2800D, T2802D .....		75	250	—	
T2800E, T2802E .....		65	225	—	
T2800M, T2802M .....		60	200	—	
T2800N, T2802N .....		40	100	—	
DC Gate-Trigger Current: <sup>‡</sup> For $V_D = 12\text{ V (dc)}$ , $R_L = 30\ \Omega$ , $T_C = 25^\circ\text{C}$ Mode $V_{\text{MT2}}$ $V_G$ I+ positive positive T2800 series T2802 series III- negative negative T2800 series T2802 series I- positive negative T2800 series only IIi+ negative positive T2800 series only For other case temperatures .....	$I_{\text{GT}}$	— — — —	10 25 15 25	25 50 25 50	mA
— —		20 30	60 60		
DC Gate-Trigger Voltage: <sup>‡</sup> For $V_D = 12\text{ V (dc)}$ , $R_L = 30\ \Omega$ , $T_C = 25^\circ\text{C}$ .....	$V_{\text{GT}}$	—	1.25	2.5	V
For other case temperatures For $V_D = V_{\text{DROM}}$ , $R_L = 125\ \Omega$ , $T_C = 125^\circ\text{C}$		0.2	—	—	
Gate-Controlled Turn-On Time: For $V_D = V_{\text{DROM}}$ , $I_{\text{GT}} = 80\text{ mA}$ , $t_r = 0.1\ \mu\text{s}$ , $i_T = 10\text{ A (peak)}$ , $T_C = 25^\circ\text{C}$ .....	$t_{\text{GT}}$	—	1.6	2.5	$\mu\text{s}$
Thermal Resistance: Junction-to-Case .....	$R_{\text{JC}}$	—	—	2.2	$^\circ\text{C/W}$
Junction-to-Ambient .....	$R_{\text{JA}}$	—	—	60	

<sup>\*</sup>For either polarity of main terminal 2 voltage ( $V_{\text{MT2}}$ ) with reference to main terminal 1.

<sup>†</sup>Variants of these devices having  $dv/dt$  characteristics selected specifically for inductive loads are available on special order; for additional information, contact your RCA Representative or your RCA Distributor.

<sup>‡</sup>For either polarity of gate voltage ( $V_G$ ) with reference to main terminal 1.

T2800, T2802 Series

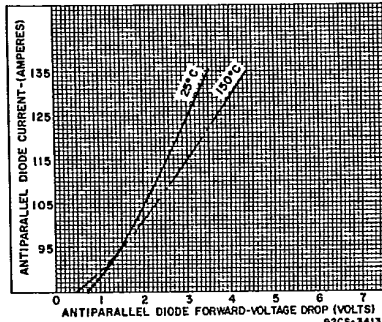


Fig. 1 — Maximum allowable case temperature vs. on-state current.

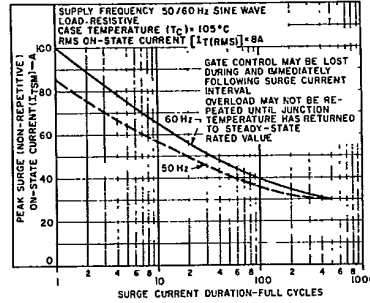


Fig. 2 — Peak surge on-state current vs. surge current duration for T2800, T2802 series.

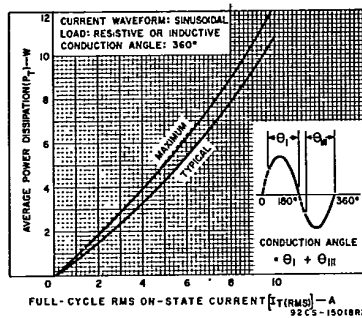


Fig. 3 — Power dissipation vs. on-state current for T2800, T2802 series.

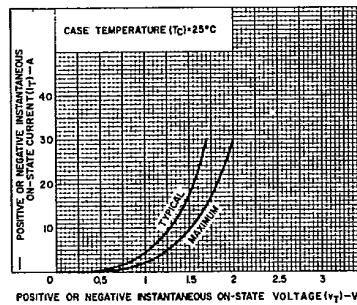


Fig. 4 — On-state current vs. on-state voltage for T2800, T2802 series.

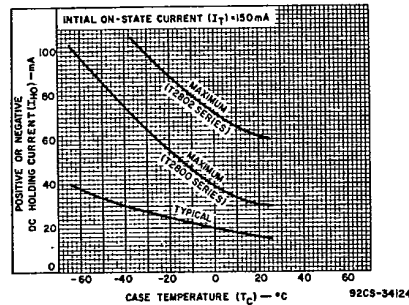


Fig. 5 — DC holding current vs. case temperature for T2800, T2802.

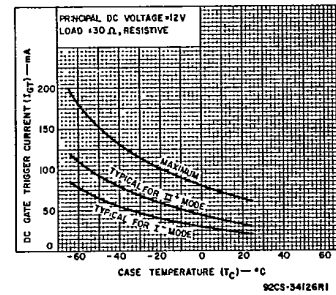


Fig. 6 — DC gate-trigger current (for I<sup>+</sup> and II<sup>+</sup> triggering modes) vs. case temperature for T2800, T2802 series.

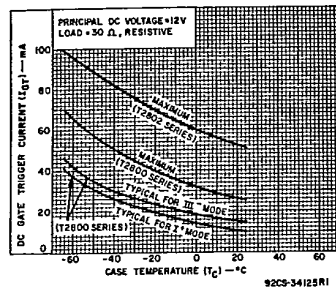


Fig. 7 — DC gate-trigger current (for I<sup>+</sup> and II<sup>+</sup> triggering modes) vs. case temperature for T2800, T2802 series.

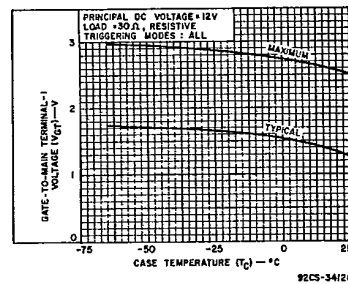


Fig. 8 — DC gate-trigger voltage vs. case temperature for T2800, T2802 series.

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